## PATENT ASSIGNMENT

Electronic Version v1.1 Stylesheet Version v1.1

SUBMISSION TYPE:	NEW ASSIGNMENT
NATURE OF CONVEYANCE:	ASSIGNMENT

## **CONVEYING PARTY DATA**

Name	Execution Date
Amos Fenigstein	04/18/2006
Yossi Netzer	04/20/2006
Ira Naot	05/21/2006
Myriam Buchbinder	07/05/2006
Avi Ben-Guigui	07/10/2006

### **RECEIVING PARTY DATA**

Name:	Tower Semiconductor Ltd.	
Street Address:	Ramat Gabriel Industrial Area	
City:	Migdal Haemek	
State/Country:	ISRAEL	
Postal Code:	23105	

### PROPERTY NUMBERS Total: 1

Property Type	Number
Application Number:	11326582

## **CORRESPONDENCE DATA**

Fax Number: (408)451-5908

Correspondence will be sent via US Mail when the fax attempt is unsuccessful.

Phone: (925) 371-8186

Email: creddick@beverlaw.com

Correspondent Name: Bever, Hoffman & Harms, LLP

Address Line 1: 1432 Concannon Blvd., Bldg. G

Address Line 4: Livermore, CALIFORNIA 94550

ATTORNEY DOCKET NUMBER:	TSL-153
-------------------------	---------

NAME OF SUBMITTER: E. Eric Hoffman

PATENT REEL: 017977 FRAME: 0278

500129092

DP \$40.00 11326

Total Attachments: 1

source=TSL-153-PTO-ASGN#page1.tif

PATENT REEL: 017977 FRAME: 0279

#### **ASSIGNMENT**

For good and valuable consideration, receipt of which is hereby acknowledged, we

Amos Fenigstein	of Ramat Gabriel Industrial Area (P.O. Box 619) Migdal Haemek, Israel 23105
Zohar Kuritsky	of Ramat Gabriel Industrial Area (P.O. Box 619) Migdal Haemek, Israel 23105
Asaf Lahav	of Ramat Gabriel Industrial Area (P.O. Box 619) Migdal Haemek, Israel 23105
<u>Ira Naot</u>	of Ramat Gabriel Industrial Area (P.O. Box 619) Migdal Haemek, Israel 23105
Yakov Roizin	of Ramat Gabriel Industrial Area (P.O. Box 619) Migdal Haemek, Israel 23105

hereby sell, assign and transfer to **Tower Semiconductor Ltd.**, an Israeli corporation, having a place of business at Ramat Gabriel Industrial Area, Migdal Haemek, 23105 Israel, its successors and assigns, the entire right, title and interest throughout the world in our invention in

# "THREE DIMENSIONAL CONTROL-GATE ARCHITECTURE FOR SINGLE POLY EPROM MEMORY DEVICES FABRICATED IN PLANAR CMOS TECHNOLOGY"

for which a United States patent application was filed on January 4, 2006, Serial No.: 11/326,582, and all patent applications and patents of every country for said invention, including divisions, reissues, continuations and extensions thereof, and all rights of priority resulting from the filing of said applications; we authorize the abovenamed assignee to apply for patents of foreign countries for said invention, and to claim all rights of priority without further authorization from us; we agree to execute all papers useful in connection with said United States and foreign applications, and generally to do everything possible to aid said assignee, their successors, assigns and nominees, at their request and expense, in obtaining and enforcing patents for said invention in all countries; and we request the Commissioner of Patents and Trademarks to issue all patents granted for said invention to the above-named assignee, its successors and assigns.

Executed this 25 day of July	, 2006.
	Amos Fenigstein
Signature Witness 1: Hymer Assit (Print name)	Signature Witness 2: College Hashard; (Print name)
Executed this 9 day of July	, 2006. Zohar Kuritsky
Signature Witness 1: Livner Assif (Print name)	Signature Witness 2: Calla fashara,
Executed this C day of	, 2006. Asaf Lahav
Signature Witness 1: Linex Assif (Print name)	Signature Witness 2: Galia Hashards (Print name)
Executed this 5 day of July	, 2006.
Signature Witness 1: James Hossif (Print name)	Signature Witness 2: (Print name)
Executed this 20 day of April	, 2006. Yakov Roizin
Signature Witness 1: hime 17514 (Print name)	Signature Witness 2: Celia Hasharon

RECORDED: 07/21/2006

PATENT REEL: 017977 FRAME: 0280